# 2SB857, 2SB858

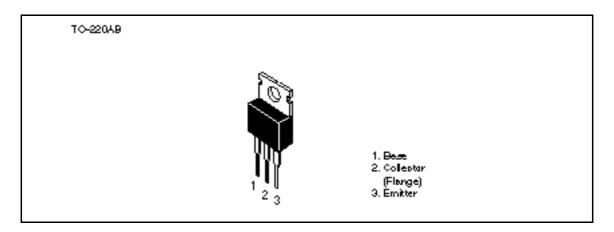
## Silicon PNP Triple Diffused

# HITACHI

### **Application**

Low frequency power amplifier complementary pair with 2SD1133 and 2SD1134

#### **Outline**



### **Absolute Maximum Ratings** ( $Ta = 25^{\circ}C$ )

		Ratings		
Item	Symbol	2SB857	2SB858	Unit
Collector to base voltage	$V_{\scriptscriptstyle{CBO}}$	<del>-7</del> 0	<del>-7</del> 0	V
Collector to emitter voltage	$V_{\text{CEO}}$	-50	-60	V
Emitter to base voltage	$V_{EBO}$	<b>-</b> 5	<b>–</b> 5	V
Collector current	I <sub>c</sub>	-4	-4	А
Collector peak current	I <sub>C(peak)</sub>	-8	-8	А
Collector power dissipation	P <sub>c</sub> *1	40	40	W
Junction temperature	Tj	150	150	°C
Storage temperature	Tstg	-45 to +150	-45 to +150	°C

Note: 1. Value at  $T_c = 25^{\circ}C$ 



### 2SB857, 2SB858

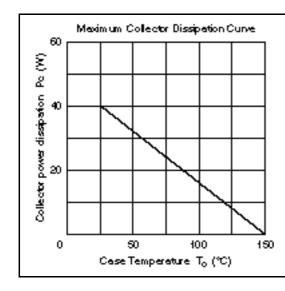
### **Electrical Characteristics** (Ta = $25^{\circ}$ C)

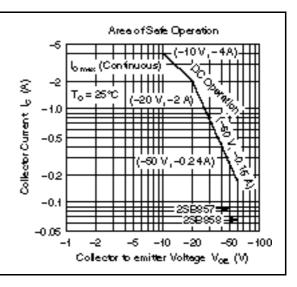
		2SB8	57		2SB858				
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	<b>-70</b>	_	_	-70	_	_	V	$I_{c} = -10 \mu A, I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	<b>-</b> 50	_	_	-60	_	_	V	$I_{\rm C}$ = -50 mA, $R_{\rm BE}$ =
Emitter to base breakdown voltage	$V_{(BR)EBO}$	<b>-</b> 5	_	_	<b>-</b> 5	_	_	V	$I_{E} = -10 \ \mu\text{A}, \ I_{C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	-1	_	_	-1	μΑ	$V_{CB} = -50 \text{ V}, I_{E} = 0$
DC current transfer ratio	h <sub>FE1</sub> *1	60	_	320	60	_	320		$V_{CE} = I_{C} = -1 A^{*2}$
	h <sub>FE2</sub>	35	_	_	35	_	_		$-4 \text{ V}$ $I_{\text{C}} = -0.1 \text{ A}^{*2}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	_	-1	_	_	-1	V	$I_{\rm C} = -2 \text{ A}, I_{\rm B} = -0.2 \text{ A}^{*2}$
Base to emitter voltage	$V_{BE}$	_	_	-1	_	_	-1	V	$V_{CE} = -4 \text{ V}, I_{C} = -1 \text{ A}^{*2}$
Gain bandwidth product	f <sub>⊤</sub>	_	15	_	_	15	_	MHz	$V_{CE} = -4 \text{ V},$ $I_{C} = -0.5 \text{ A}^{*2}$

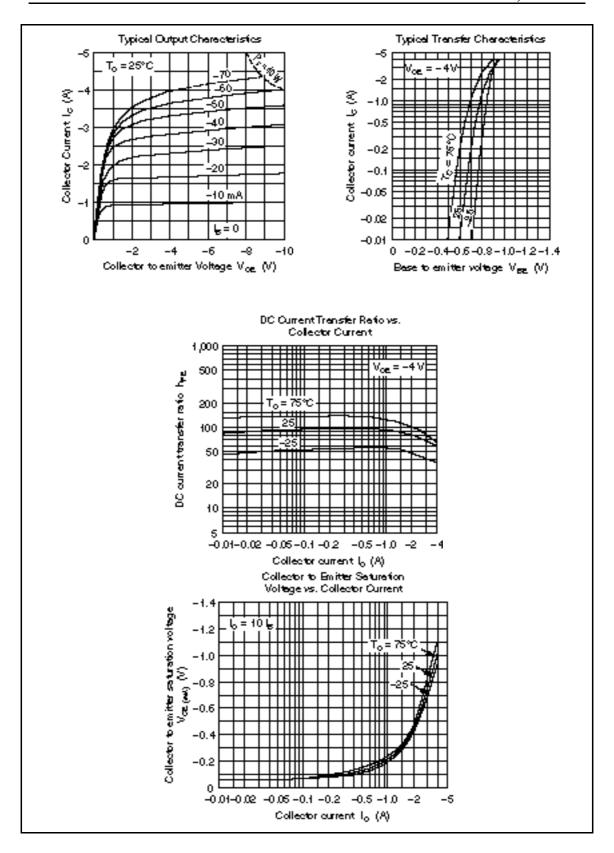
Notes: 1. The 2SB857 and 2SB858 are grouped by  $h_{\text{FE1}}$  as follows.

2. Pulse test

В	С	D
60 to 120	100 to 200	160 to 320







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